

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|--------------------------------|------------------|---------|------------------|
| L1 | 1 | FinFET and hydrogen near5 (implanted or dopant) near5 (semiconductor or silicon) | USPAT; EPO; JPO; DERWENT | OR | OFF | 2004/12/05 18:14 |
| L2 | 46 | MOSFET and hydrogen near5 (implanted or dopant) near5 (semiconductor or silicon) | USPAT; EPO; JPO; DERWENT | OR | OFF | 2004/12/05 18:15 |